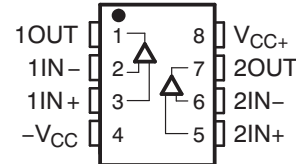


LOW-NOISE ADSL DUAL DIFFERENTIAL RECEIVER

FEATURES

- ADSL Differential Receiver
- Low $1.6 \text{ nV}/\sqrt{\text{Hz}}$ Voltage Noise
- High Speed
 - 100 MHz Bandwidth [–3 dB, $G = 2$ (–1)]
 - 100 V/ μs Slew Rate
- 90 mA Output Drive (Typ)
- Very Low Distortion
 - THD = –72 dBc ($f = 1 \text{ MHz}$, $R_L = 150 \Omega$)
 - THD = –90 dBc ($f = 1 \text{ MHz}$, $R_L = 1 \text{ k}\Omega$)
- 5 V, $\pm 5 \text{ V}$ to $\pm 15 \text{ V}$ Typical Operation
- Available in Standard SOIC or MSOP PowerPAD™ Package

SOIC (D) AND MSOP PowerPAD (DGN) PACKAGE
(TOP VIEW)



Cross Section View of DGN Package

DESCRIPTION

The THS6062 is a high-speed differential receiver designed for ADSL data communication systems. Its very low $1.6 \text{ nV}/\sqrt{\text{Hz}}$ voltage noise provides the high signal-to-noise ratios necessary for the long transmission lengths of ADSL systems over copper telephone lines. In addition, this receiver operates with a very low distortion of –90 dBc ($f = 1 \text{ MHz}$, $R_L = 1 \text{ k}\Omega$), exceeding the distortion requirements of ADSL CODECs. The THS6062 is a voltage feedback amplifier offering a high 100-MHz bandwidth and 100-V/ μs slew rate and is stable at gains of 2(–1) or greater. It operates over a wide range of power supply voltages including 5 V and $\pm 5 \text{ V}$ to $\pm 15 \text{ V}$. This device is available in standard SOIC or MSOP PowerPAD package. The small, surface-mount, thermally-enhanced MSOP PowerPAD package is fully compatible with automated surface-mount assembly procedures.

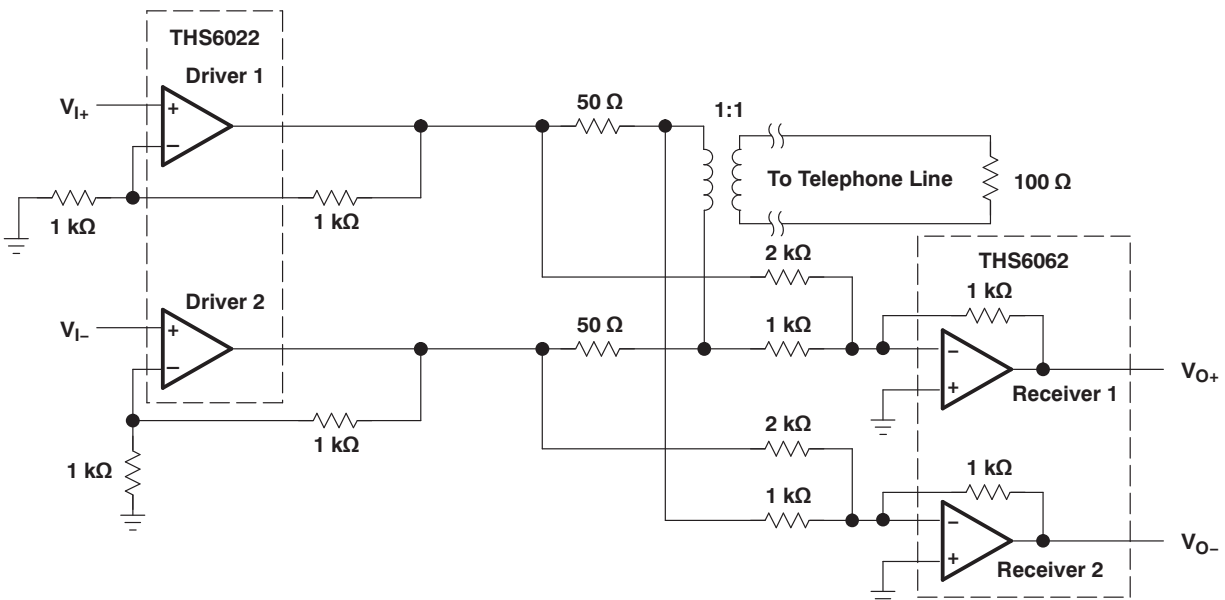


Figure 1. Typical Client-Side ADSL Application



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.

PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas Instruments reserves the right to change or discontinue these products without notice.

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PRODUCT PREVIEW



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

HIGH-SPEED XDSL LINE DRIVER/RECEIVER FAMILY

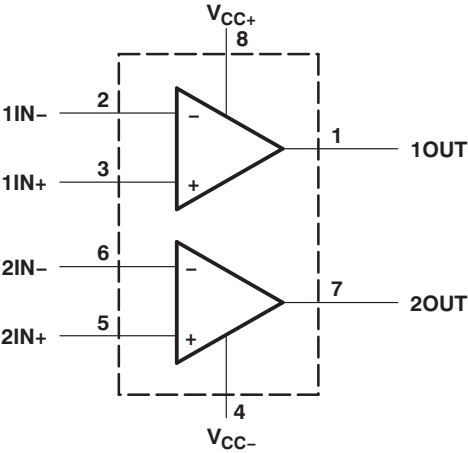
DEVICE	DRIVER	RECEIVER	5 V	±5 V	±15 V	BW (MHz)	SR (V/μs)	THD f = 1 MHz (dB)	I _O (mA)	V _n (nV/√Hz)
THS6002	•	•		•	•	140	1000	–62	500	1.7
THS6012	•			•	•	140	1300	–65	500	1.7
THS6022	•			•	•	210	1900	–66	250	1.7
THS6062		•	•	•	•	100	100	–72	90	1.6
THS7002		•		•	•	70	100	–84	25	2.0

AVAILABLE OPTIONS

T _A	PACKAGED DEVICES			
	PLASTIC SMALL OUTLINE ⁽¹⁾ (D)	PowerPAD PLASTIC MSOP ⁽¹⁾ (DGN)	MSOP SYMBOL	EVALUATION MODULE
0°C to 70°C	THS6062CD	THS6062CDGN	TIABE	THS6062EVM
–40°C to 85°C	THS6062ID	THS6062IDGN	TIABH	—

(1) The D and DGN packages are available taped and reeled. Add an R suffix to the device type (i.e., THS6062CDGNR).

FUNCTIONAL BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		VALUE	UNIT
V_{CC+} to V_{CC-}	Supply voltage	33	V
V_I	Input voltage	$\pm V_{CC}$	
I_O	Output current	150	mA
V_{IO}	Differential input voltage	± 4	V
	Continuous total power dissipation	See Dissipation Rating Table	
T_A	Operating free-air temperature	C-suffix	0°C to 70
		I-suffix	–40 to 85
T_J	Maximum junction temperature	150	°C
T_{stg}	Storage temperature	–65 to 150	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS

PACKAGE	θ_{JA} (°C/W)	θ_{JC} (°C/W)	$T_A = 25^\circ\text{C}$ POWER RATING
D	167 ⁽¹⁾	38.3	740 mW
DGN ⁽²⁾	58.4	4.7	2.14 W

- (1) This data was taken using the JEDEC standard Low-K test PCB. For the JEDEC Proposed High-K test PCB, the θ_{JA} is 95°C/W with a power rating at $T_A = 25^\circ\text{C}$ of 1.32 W.
- (2) This data was taken using 2 oz. trace and copper pad that is soldered directly to a 3 in. × 3 in. PC. For further information, refer to Application Information section of this data sheet.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
V_{CC+} and V_{CC-}	Supply voltage	Dual supply		± 2.5	V
		Single supply		5	
T_A	Operating free-air temperature	C-suffix		0	°C
		I-suffix		–40	

ELECTRICAL CHARACTERISTICSAt $T_A = 25^\circ\text{C}$, $V_{CC} = \pm 15\text{ V}$, $R_L = 150\ \Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
V _{CC}	Supply voltage operating range	Dual supply		±2.25		±16.5	V
		Single supply		4.5		33	
I _{CC}	Supply current (per amplifier)	V _{CC} = ±15 V	T _A = 25°C	8.5		10	mA
			T _A = full range			11	
		V _{CC} = ±5 V	T _A = 25°C	7.5		9	mA
			T _A = full range			10.5	
		V _{CC} = ±2.5 V	T _A = 25°C	7.3		9	mA
			T _A = full range			10.5	
V _O	Output voltage swing	V _{CC} = ±15 V	R _L = 1 Ω	±13	±13.6		V
		V _{CC} = ±5 V		±3.4	±3.8		
		V _{CC} = ±2.5 V		±1	±1.3		
		V _{CC} = ±15 V	R _L = 250 Ω	±12	±12.9		
		V _{CC} = ±5 V	R _L = 150 Ω	±3	±3.5		
		V _{CC} = ±2.5 V		±0.9	±1.2		
I _O	Output current ⁽²⁾	V _{CC} = ±15 V	R _L = 20 Ω	60	90		mA
		V _{CC} = ±5 V		50	70		
		V _{CC} = ±2.5 V		40	55		
I _{SC}	Short-circuit current ⁽²⁾	V _{CC} = ±15 V			150		mA
V _{IO}	Input offset voltage	V _{CC} = ±5 V or V _{CC} = ±15 V	T _A = 25°C	1.5		6	mV
			T _A = full range			8	
	Offset drift	V _{CC} = ±5 V or V _{CC} = ±15 V	T _A = full range	20			μV/°C
I _{IB}	Input bias current	V _{CC} = ±5 V or V _{CC} = ±15 V	T _A = 25°C	3		6	μA
			T _A = full range			8	
I _{OS}	Input offset current	V _{CC} = ±5 V or V _{CC} = ±15 V	T _A = 25°C	30		250	nA
			T _A = full range			400	
	Offset current drift	V _{CC} = ±5 V or V _{CC} = ±15 V	T _A = full range	0.3			nA/°C
CMRR	Common mode rejection ratio	V _{CC} = ±15 V, V _{ICR} = ±12 V	T _A = 25°C	85		95	dB
			T _A = full range	80			
		V _{CC} = ±5 V, V _{ICR} = ±2.5 V	T _A = 25°C	90		100	
			T _A = full range	85			
PSRR	Power supply rejection ratio	V _{CC} = ±5 V or ±15 V	T _A = 25°C	85		95	dB
			T _A = full range	80			
V _{ICR}	Common-mode input voltage range	V _{CC} = ±15 V		±13.5	±14.3		V
		V _{CC} = ±5 V		±3.8	±4.3		
		V _{CC} = ±2.5 V		±1.4	±1.8		
R _I	Input resistance				2		MΩ
C _I	Input capacitance				1.5		pF
R _O	Output resistance	Open loop			13		Ω
	Open loop gain	V _{CC} = ±5 V, V _O = ±10 V, R _L = 1 kΩ	T _A = 25°C	40		70	V/mV
			T _A = full range	35			
		V _{CC} = ±5 V, V _O = ±2.5 V, R _L = 1 kΩ	T _A = 25°C	35		50	V/mV
			T _A = full range	30			

(1) Full range = 0°C to 70°C for the THS6062C and -40°C to 85°C for the THS6062I.

(2) Observe power dissipation ratings to keep the junction temperature below absolute maximum ratings when the output is heavily loaded or shorted. See the absolute maximum ratings section for more information.

OPERATING CHARACTERISTICS

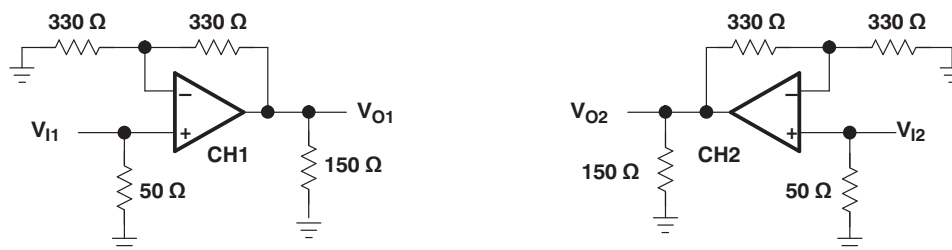
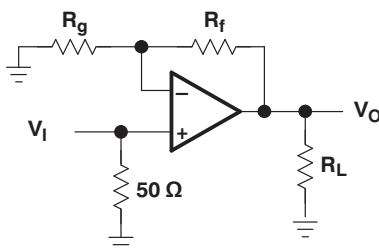
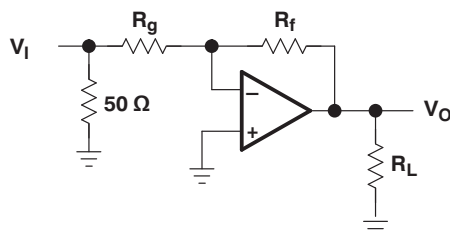
At $T_A = 25^\circ\text{C}$, $V_{CC} = \pm 15\text{ V}$, $R_L = 150\ \Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
SR	Slew rate ⁽²⁾	V _{CC} = ±15 V	GAIN = –1		100		V/μs
		V _{CC} = ±5 V			80		
		V _{CC} = ±2.5 V			70		
t _s	Settling time to 0.1%	V _{CC} = ±15 V, 5-V step	GAIN = –1		60		ns
		V _{CC} = ±5 V, 2.5-V step			45		
		V _{CC} = ±2.5 V, 1-V step			35		
	Settling time to 0.01%	V _{CC} = ±15 V, 5-V step	GAIN = –1		90		ns
		V _{CC} = ±5 V, 2.5-V step			80		
		V _{CC} = ±2.5 V, 1-V step			75		
THD	Total harmonic distortion	V _{CC} = ±5 V or ±15 V, V _{O(pp)} = 2 V, f = 1 MHz, Gain = 2)	R _L = 150 Ω		–72		dBc
			R _L = 1 kΩ		–90		
V _n	Input voltage noise	V _{CC} = ±5 V or ±15 V, f = 10 kHz				1.6	nV/√Hz
I _n	Input current noise	V _{CC} = ±5 V or ±15 V, f = 10 kHz				1.2	pV/√Hz
BW	Dynamic performance small-signal bandwidth (–3 dB)	V _{CC} = ±15 V	V _{O(pp)} = 0.4 V, Gain = 2, –1		100		MHz
		V _{CC} = ±5 V			90		
		V _{CC} = ±2.5 V			85		
	Bandwidth for 0.1 dB flatness	V _{CC} = ±15 V	V _{O(pp)} = 0.4 V, Gain = 2, –1		50		MHz
		V _{CC} = ±5 V			45		
		V _{CC} = ±2.5 V			40		
	Full power bandwidth ⁽³⁾	V _{O(pp)} = 20 V, V _{CC} = ±15 V	R _L = 1 kΩ		1.6		MHz
		V _{O(pp)} = 5 V, V _{CC} = ±5 V			5		
Channel-to-channel crosstalk		V _{CC} = ±5 V or ±15 V, f = 1 MHz, Gain = 2				–61	dBc

(1) Full range = 0°C to 70°C for the THS6062C and -40°C to 85°C for the THS6062I.

(2) Slew rate is measured from an output level range of 25% to 75%.

(3) Full power bandwidth = slew rate / $2\pi V_{(peak)}$

PARAMETER MEASUREMENT INFORMATION**Figure 2. THS6062 Crosstalk Test Circuit****Figure 3. Step Response Test Circuit****Figure 4. Step Response Test Circuit**

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	vs Free-air temperature	5
I_{IB}	Input bias current	vs Free-air temperature	6
V_O	Output voltage	vs Supply voltage	7
	Maximum output voltage swing	vs Free-air temperature	8
I_O	Maximum output current	vs Free-air temperature	9
I_{CC}	Supply current	vs Free-air temperature	10
V_{IC}	Common-mode input voltage	vs Supply voltage	11
Z_O	Closed-loop output impedance	vs Frequency	12
	Open-loop gain and Phase Response		13
PSRR	Power-supply rejection ratio	vs Frequency	14
CMRR	Common-mode rejection ratio	vs Frequency	15
	Voltage noise and current noise	vs Frequency	16
	Crosstalk	vs Frequency	17
	Harmonic distortion	vs Frequency	18, 19
	Harmonic distortion	vs Peak-to-peak output voltage	20, 21
SR	Slew rate	vs Free-air temperature	22
	0.1% settling time	vs Output voltage step size	23
	Output amplitude	vs Frequency	24–30
	Small and large frequency response		31–34
	1-V step response		35, 36
	4-V step response		37
	20-V step response		38

PRODUCT PREVIEW

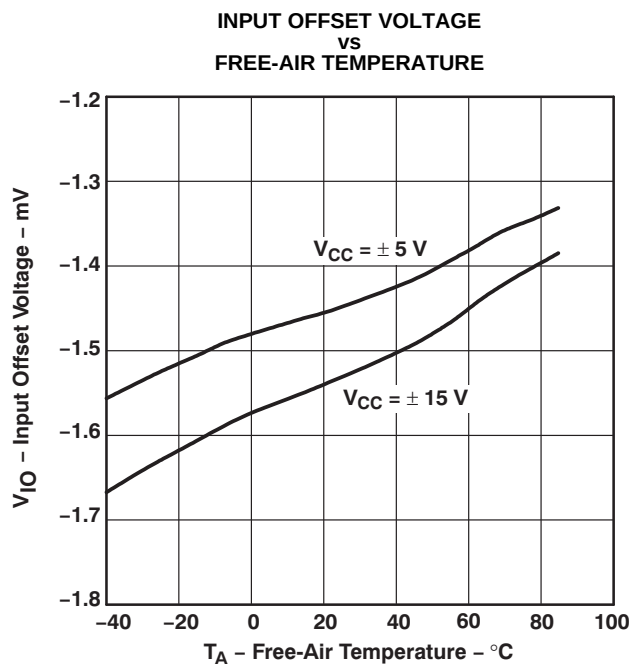


Figure 5.

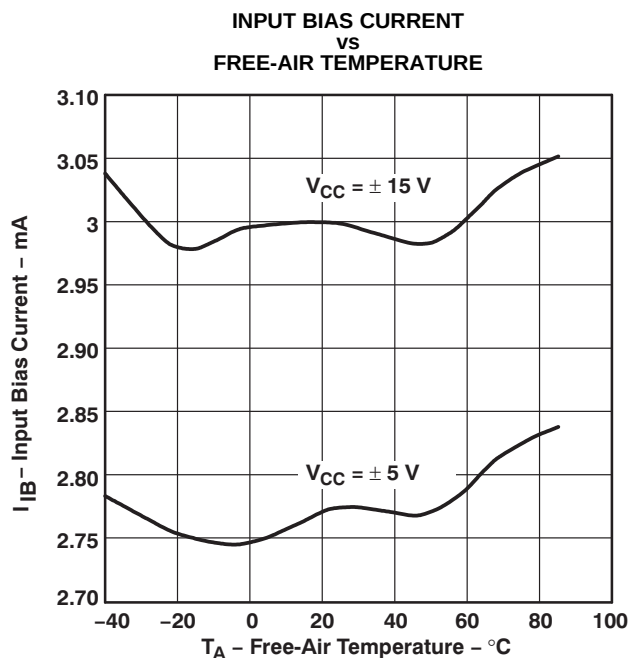


Figure 6.

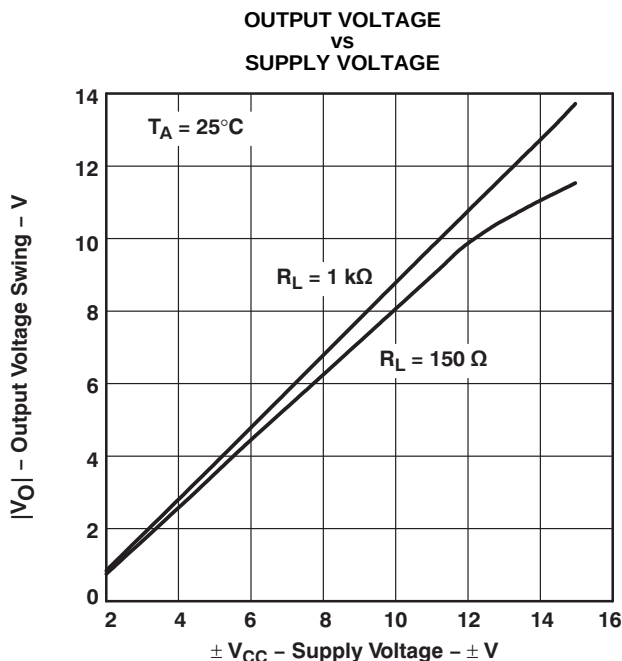


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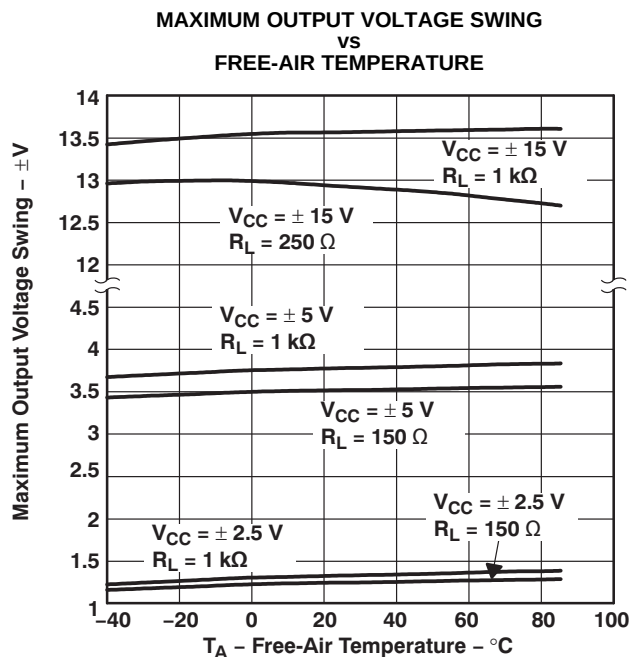


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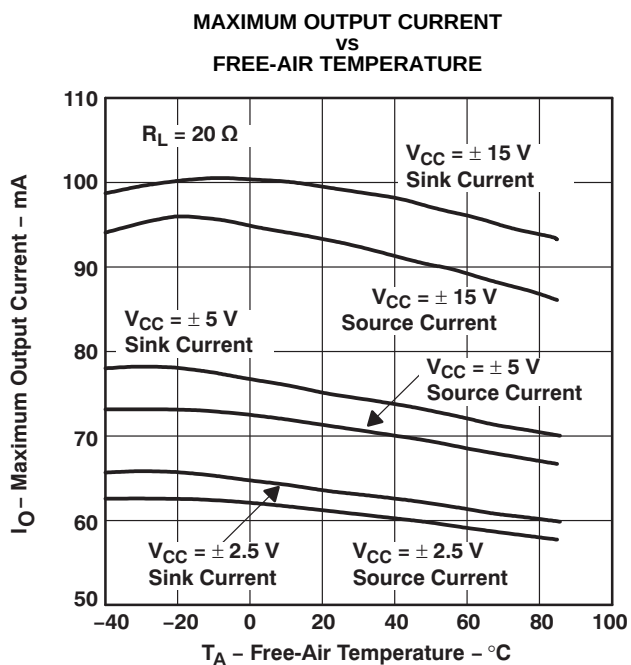


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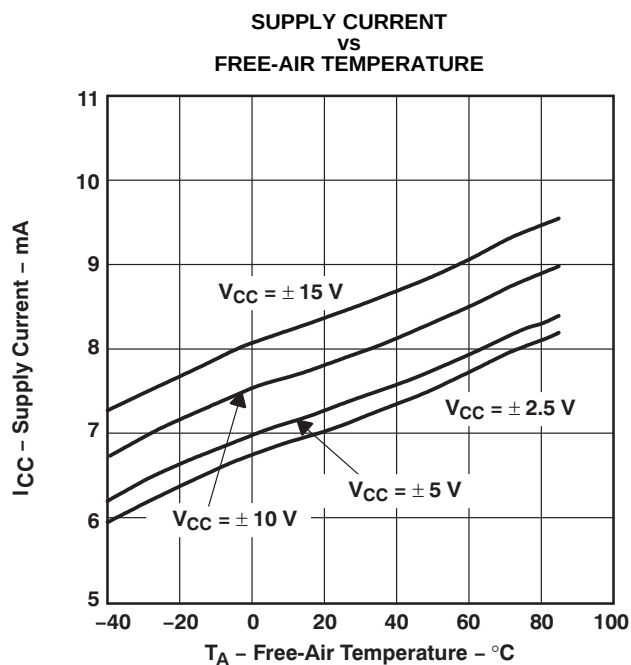


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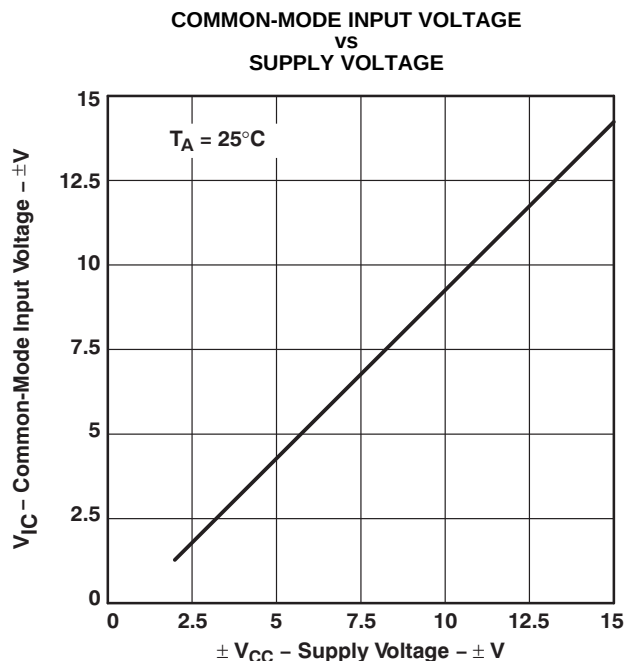


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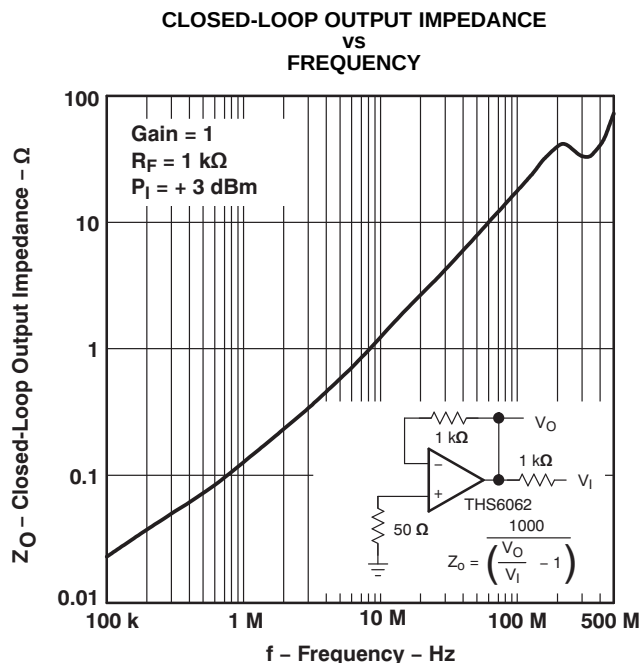


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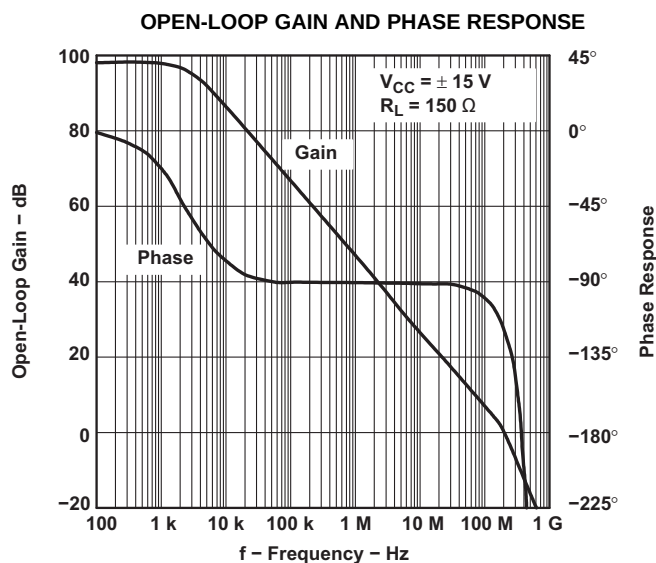


Figure 13.

**POWER-SUPPLY REJECTION RATIO
VS
FREQUENCY**

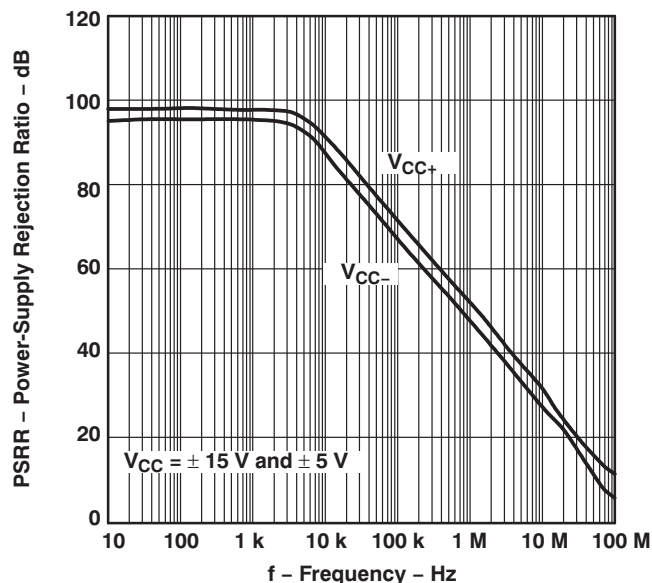


Figure 14.

**COMMON-MODE REJECTION RATIO
VS
FREQUENCY**

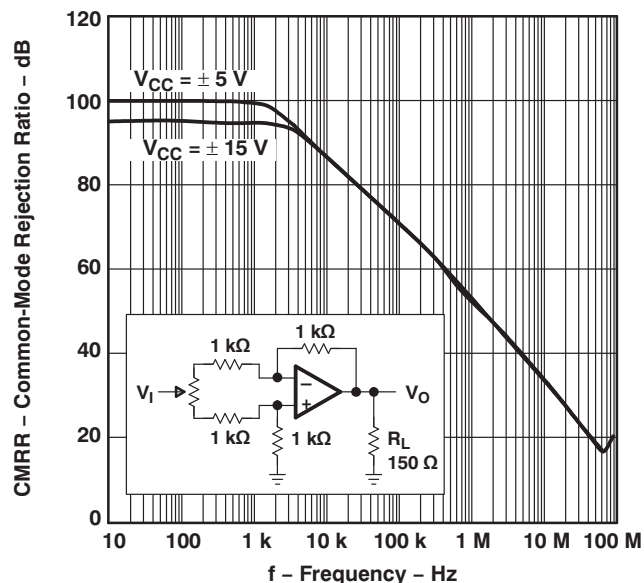


Figure 15.

**VOLTAGE NOISE AND CURRENT NOISE
VS
FREQUENCY**

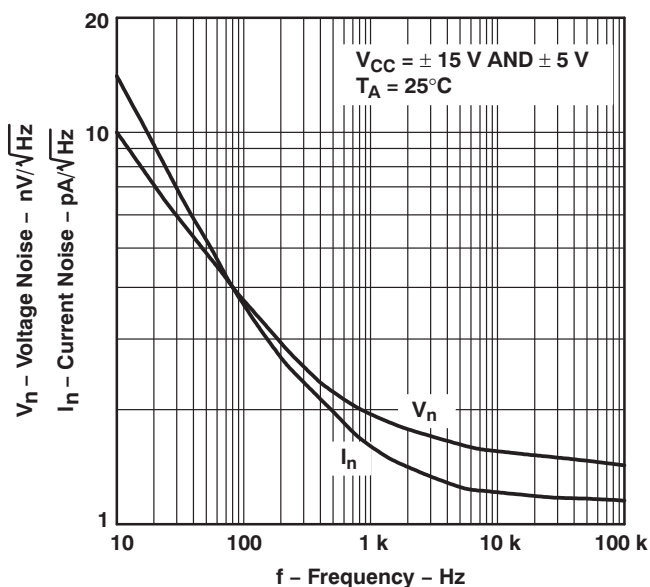


Figure 16.

**CROSSTALK
VS
FREQUENCY**

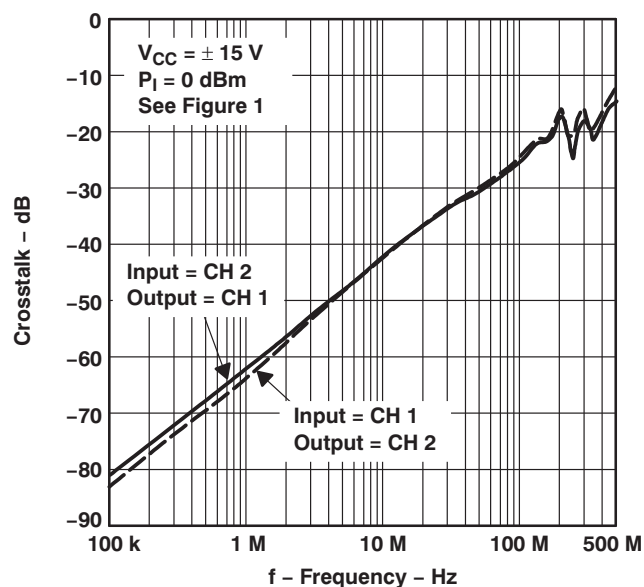


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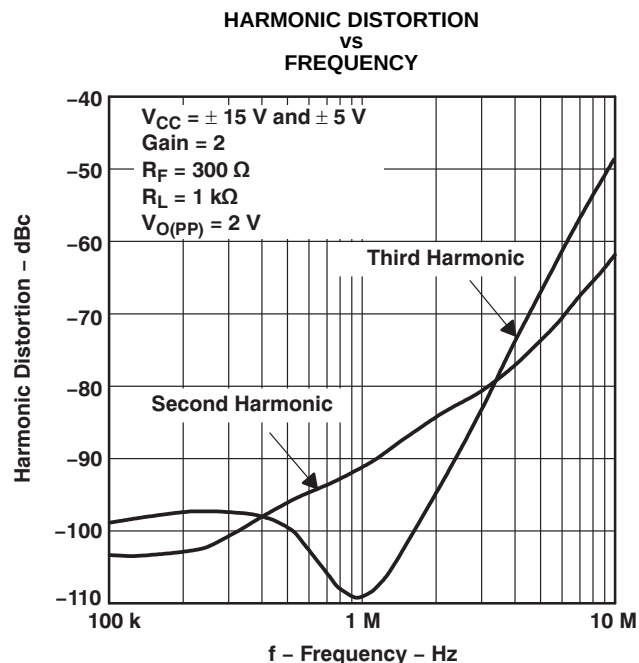


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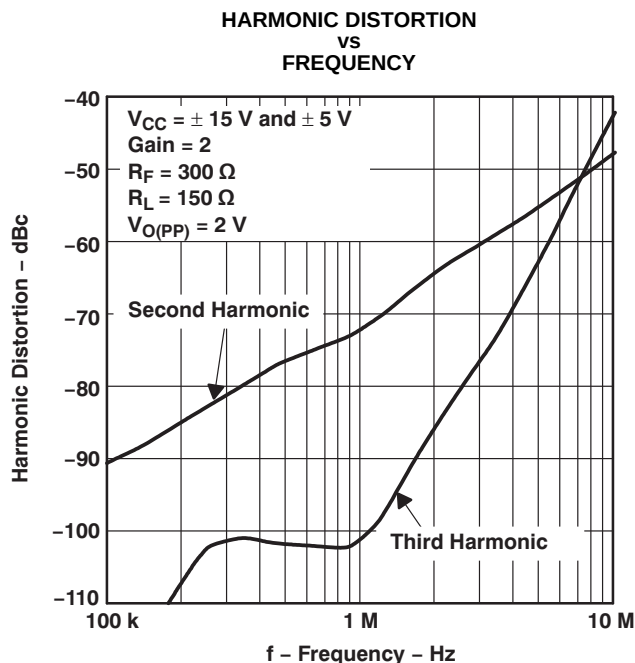


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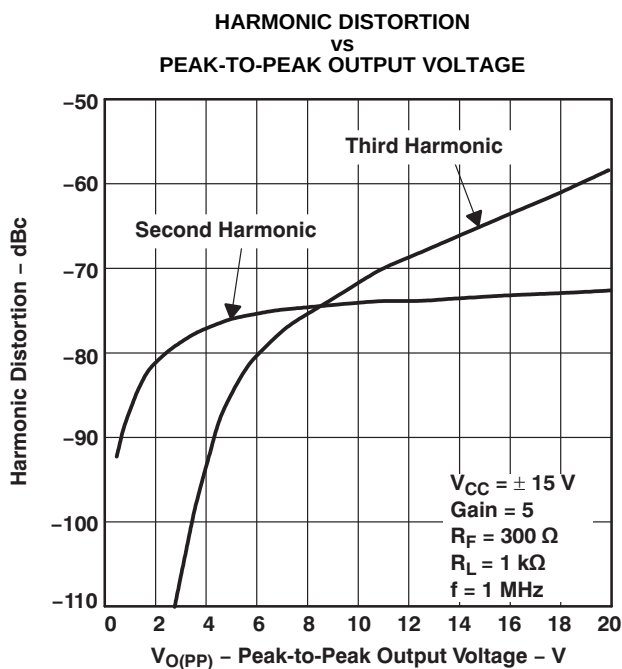


Figure 20.

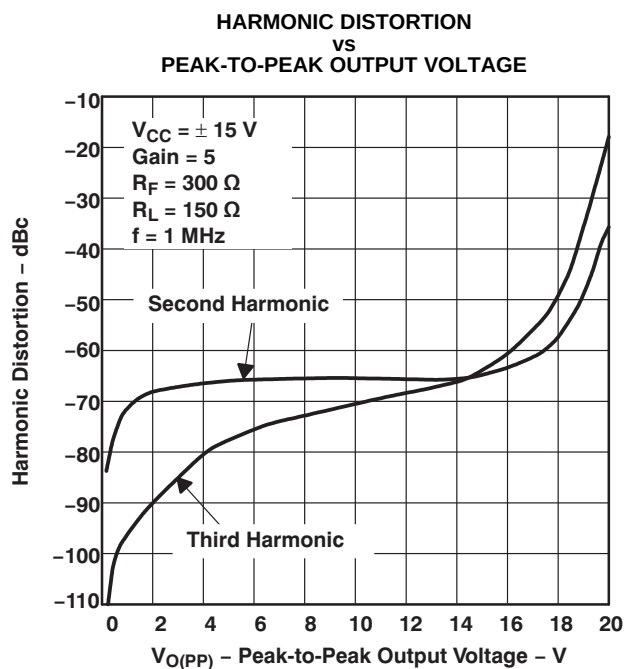


Figure 21.

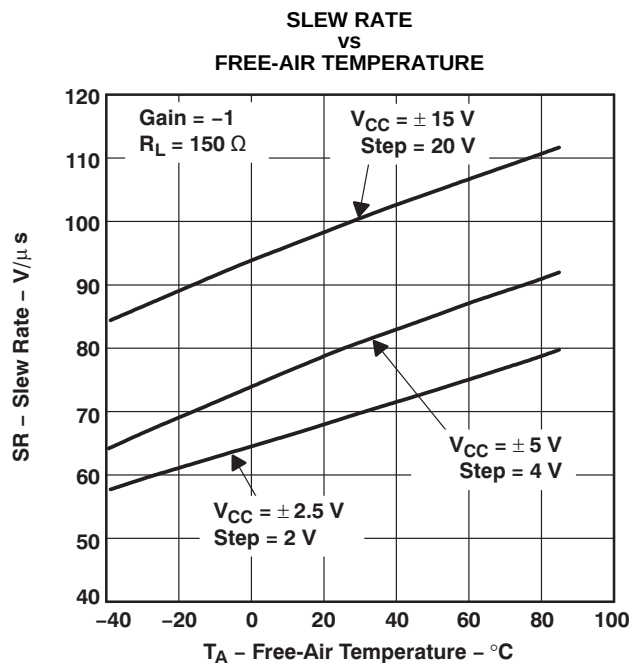


Figure 22.

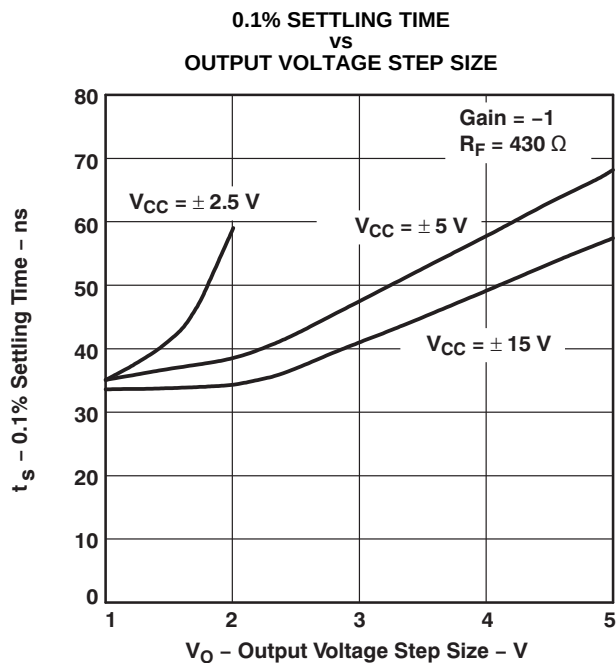


Figure 23.

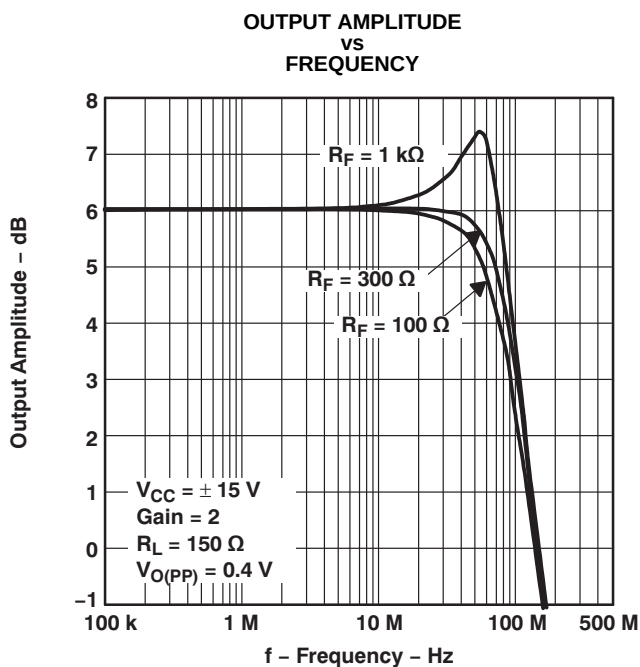


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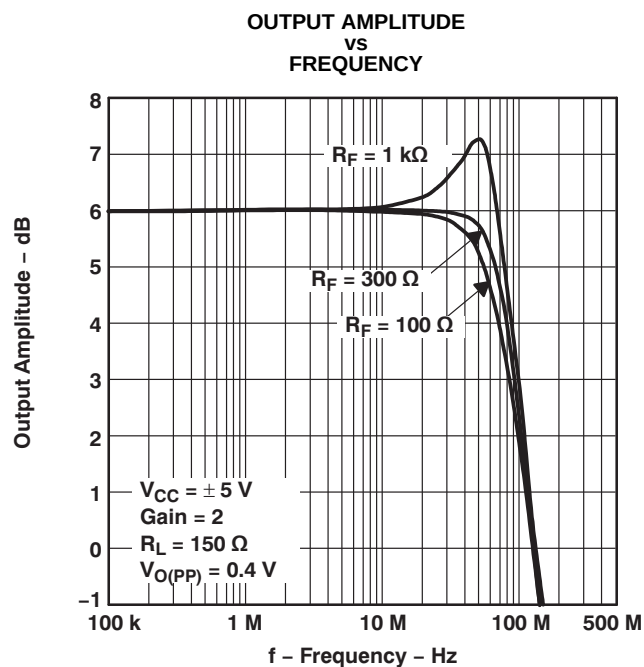


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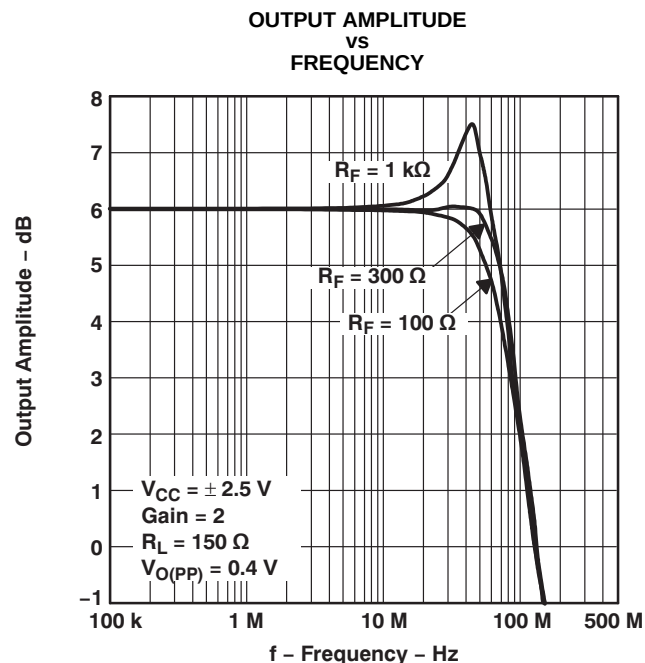


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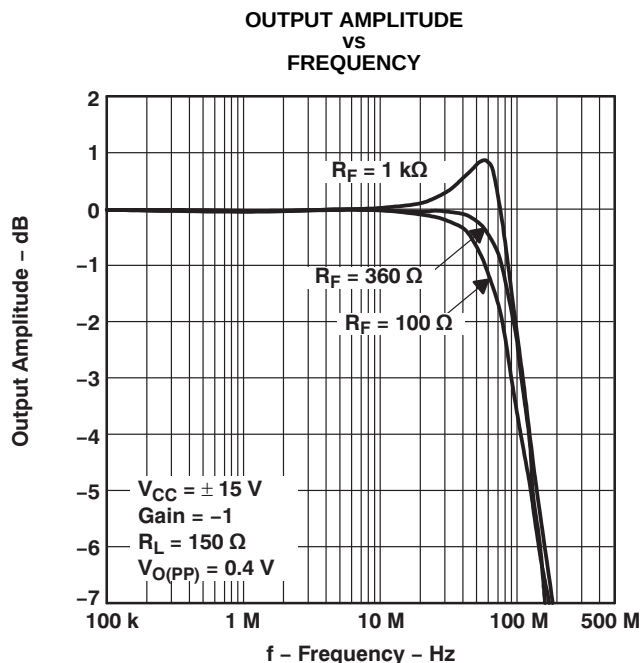


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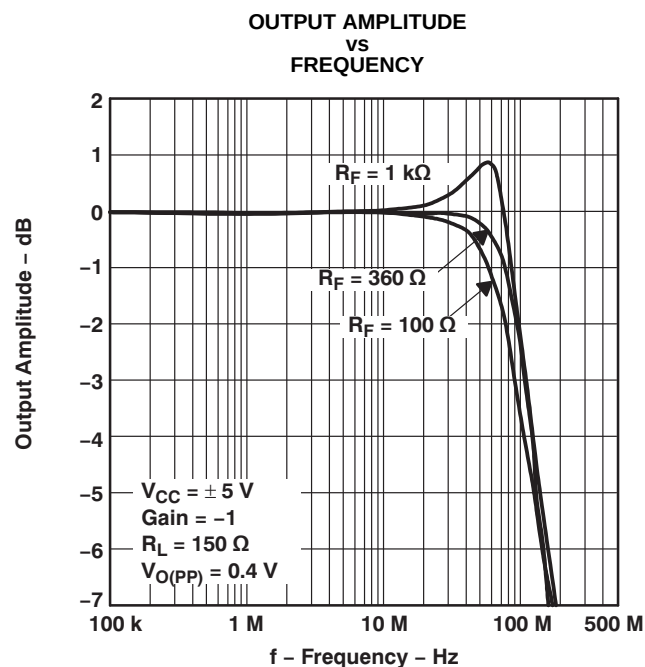


Figure 28.

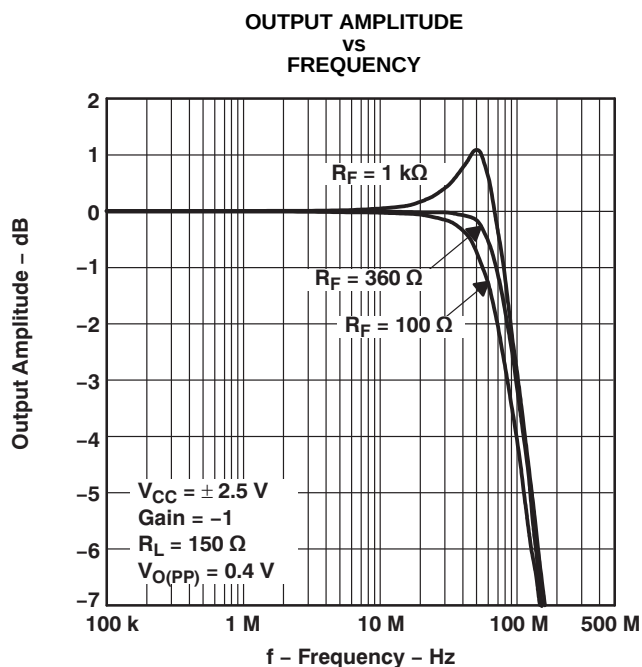


Figure 29.

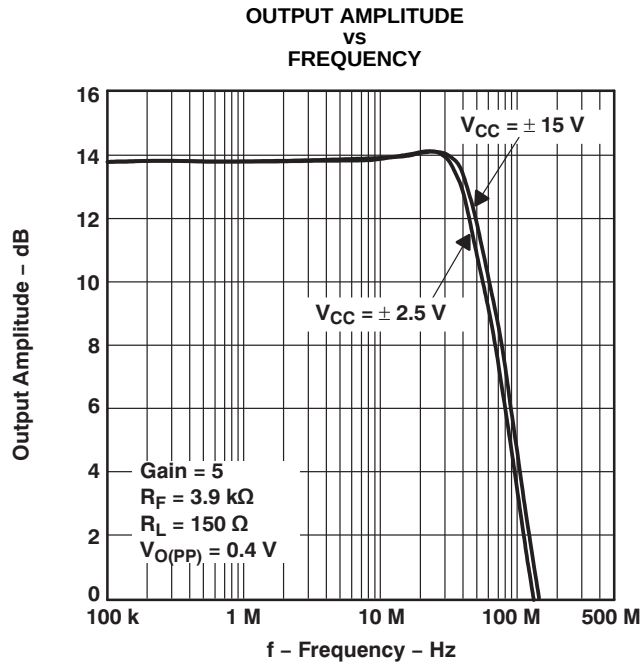


Figure 30.

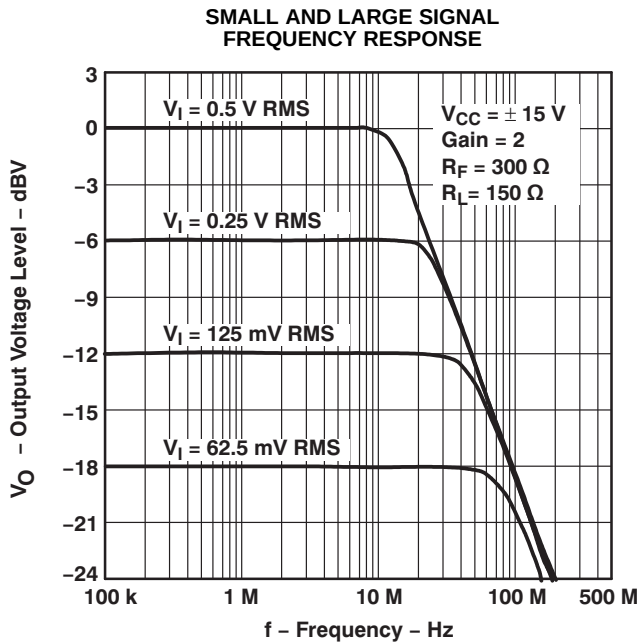


Figure 31.

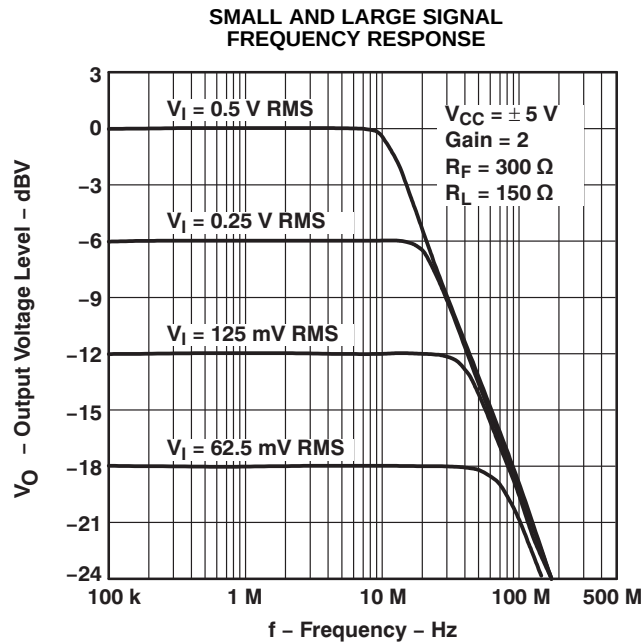


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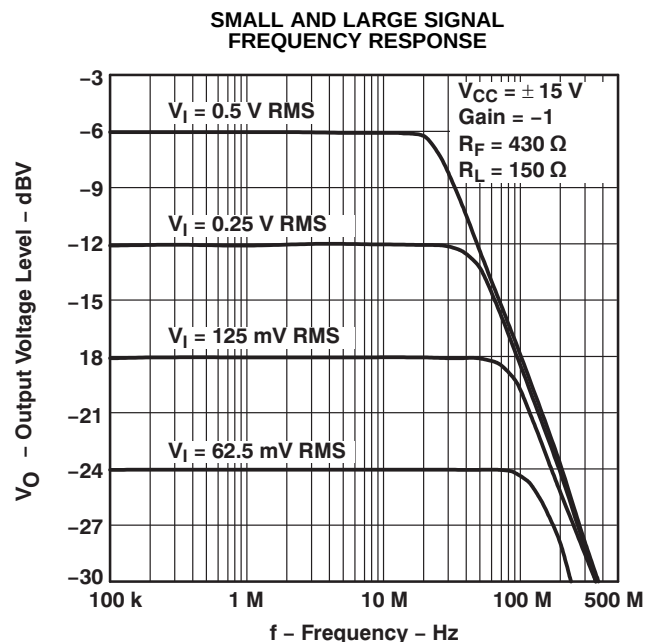


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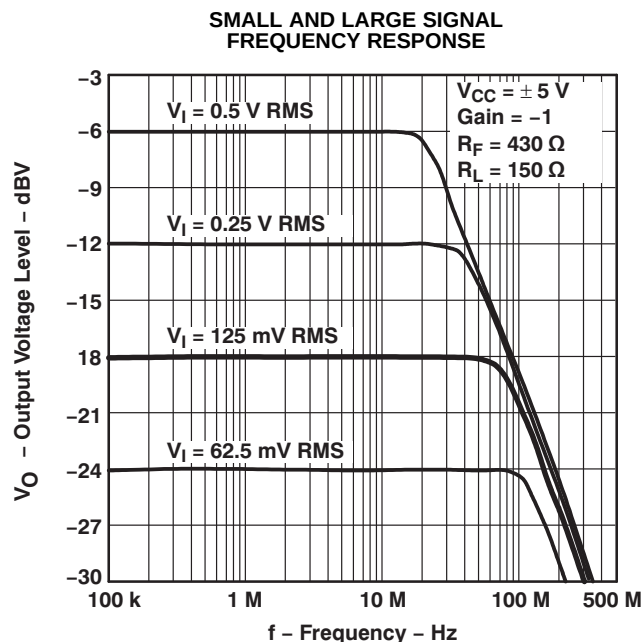


Figure 34.

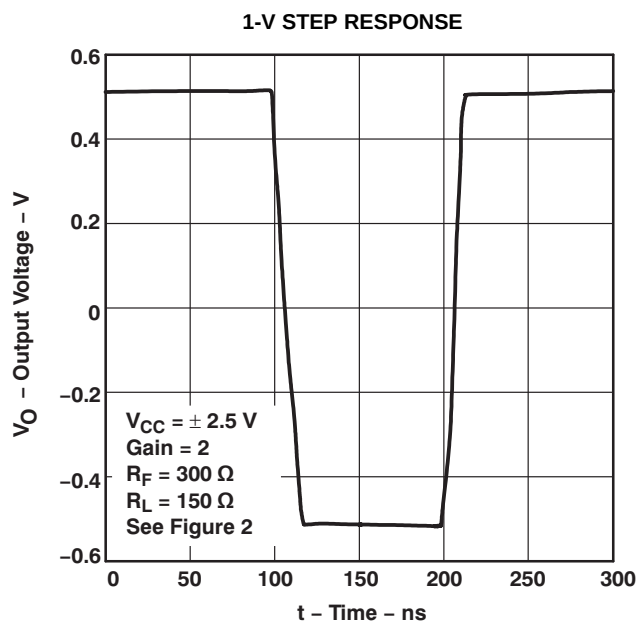


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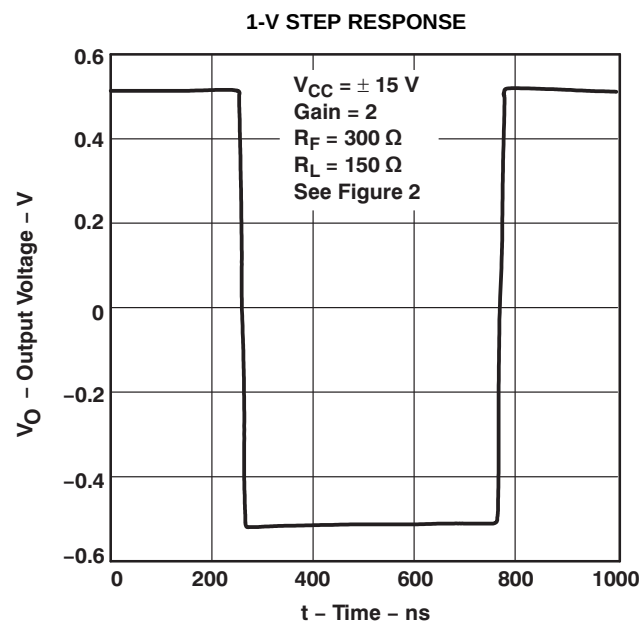


Figure 36.

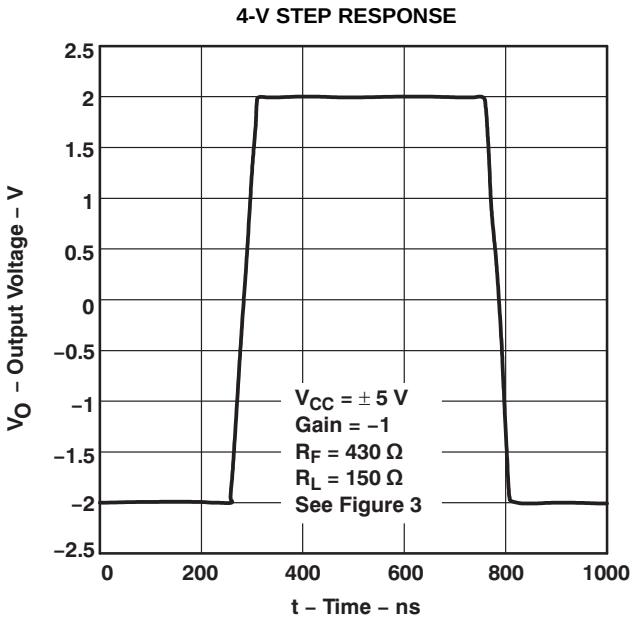


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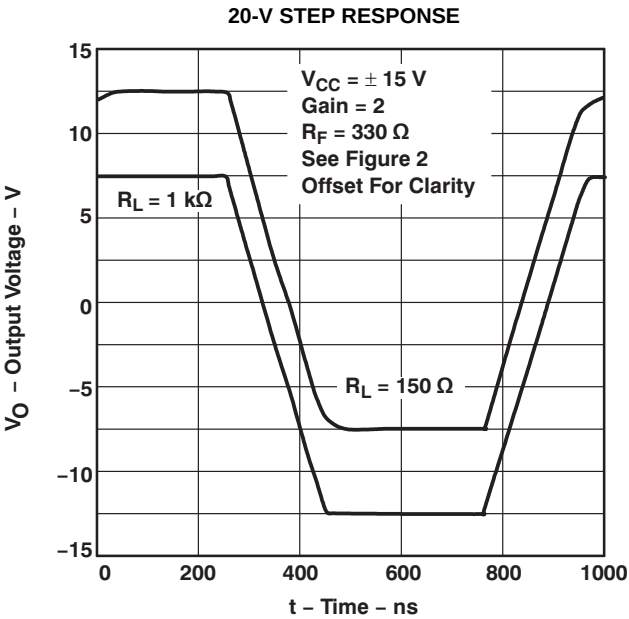


Figure 38.

One client-side terminal circuit implementation, shown in Figure 40, uses a 1:2 transformer ratio. While creating a power and output voltage advantage for the line drivers, the 1:2 transformer ratio reduces the SNR for the received signals. The ADSL standard, ANSI T1.413, stipulates a noise power spectral density of -140 dBm/Hz, which is equivalent to 31.6 nV/ $\sqrt{\text{Hz}}$ for a $100\text{-}\Omega$ system. Although many amplifiers can reach this level of performance, actual ADSL system testing has indicated that the noise power spectral density may typically be ≤ -150 dBm/Hz, or ≤ 10 nV/ $\sqrt{\text{Hz}}$. With a transformer ratio of 1:2, this number reduces to less than 5 nV/ $\sqrt{\text{Hz}}$. The THS6062, with an equivalent input noise of 1.6 nV/ $\sqrt{\text{Hz}}$, is an excellent choice for this application. Coupled with a very low 1.2 pA/ $\sqrt{\text{Hz}}$ equivalent input current noise and low value resistors, the THS6062 will ensure that the received signal SNR will be as high as possible.

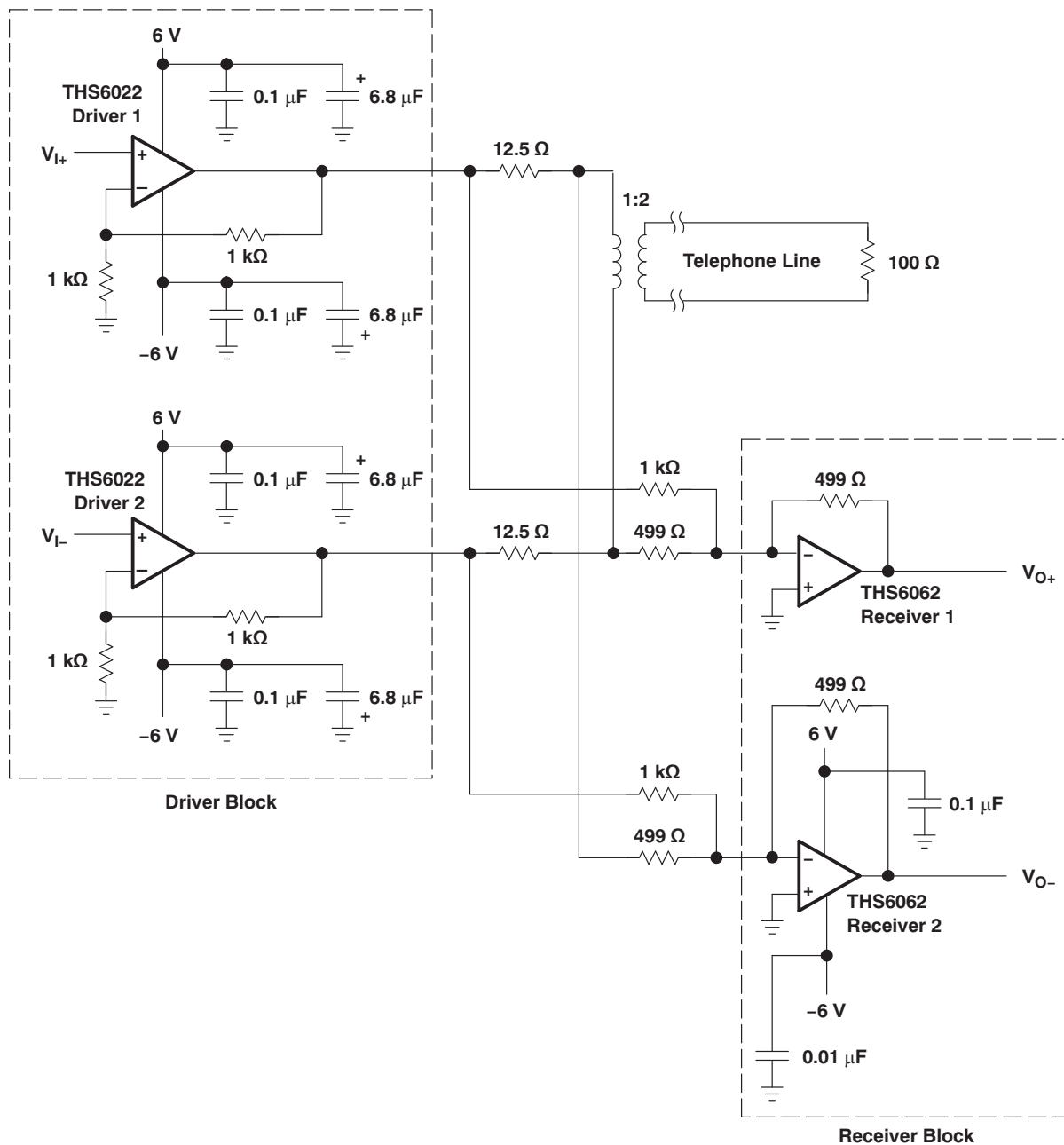


Figure 40. THS6062 Client-Side ADSL Application

NOISE CALCULATIONS AND NOISE FIGURE

Noise can cause errors on very small signals. This is especially true for the amplifying small signals. The noise model for current-feedback amplifiers (CFB) is the same as voltage-feedback amplifiers (VFB). The only difference between the two is that the CFB amplifiers generally specify different noise-current parameters for each input, while VFB amplifiers usually only specify one noise-current parameter. The noise model is shown in Figure 41. This model includes all of the noise sources as follows:

- e_n = Amplifier internal voltage noise ($\text{nV}/\sqrt{\text{Hz}}$)
- $\text{IN}+$ = Noninverting current noise ($\text{pA}/\sqrt{\text{Hz}}$)
- $\text{IN}-$ = Inverting current noise ($\text{pA}/\sqrt{\text{Hz}}$)
- e_{R_x} = Thermal voltage noise associated with each resistor ($e_{R_x} = 4 \text{ kTR}_x$)

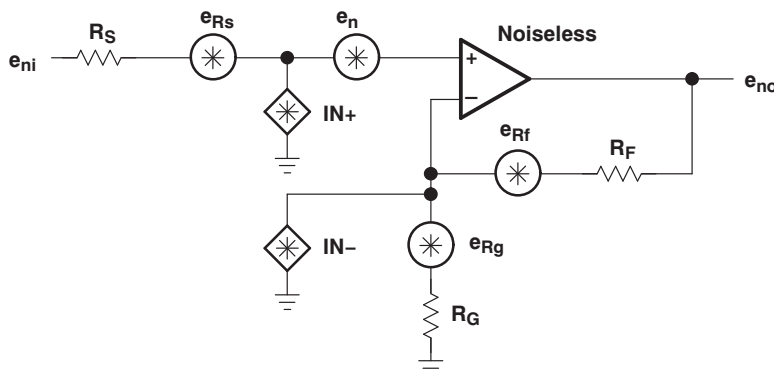


Figure 41. Noise Model

The total equivalent input noise density (e_{ni}) is calculated by using the following equation:

$$e_{ni} = \sqrt{(e_n)^2 + (\text{IN}+ \times R_S)^2 + (\text{IN}- \times (R_F \parallel R_G))^2 + 4 \text{ kTR}_S + 4 \text{ kT}(R_F \parallel R_G)} \quad (1)$$

Where:

- k = Boltzmann's constant = 1.380658×10^{-23}
- T = Temperature in degrees Kelvin ($273 + ^\circ\text{C}$)
- $R_F \parallel R_G$ = Parallel resistance of R_F and R_G

To get the equivalent output noise of the amplifier, just multiply the equivalent input noise density (e_{ni}) by the overall amplifier gain (A_V).

$$e_{no} = e_{ni} A_V = e_{ni} \left(1 + \frac{R_F}{R_G} \right) \text{ (Noninverting Case)} \quad (2)$$

As the previous equations show, to keep noise at a minimum, small-value resistors should be used. As the closed-loop gain is increased (by reducing R_G), the input noise is reduced considerably because of the parallel resistance term. This leads to the general conclusion that the most dominant noise sources are the source resistor R_S and the internal amplifier noise voltage (e_n). Because noise is summed in a root-mean-squares method, noise sources smaller than 25% of the largest noise source can be effectively ignored. This can greatly simplify the formula and make noise calculations much easier to calculate.

For more information on noise analysis, refer to the *Noise Analysis* section in *Operational Amplifier Circuits Applications Report* (SLVA043).

This brings up another noise measurement usually preferred in RF applications, the noise figure (NF). Noise figure is a measure of noise degradation caused by the amplifier. The value of the source resistance must be defined and is typically 50 Ω in RF applications.

$$NF = 10\log \left[\frac{e_{ni}^2}{(e_{Rs})^2} \right] \quad (3)$$

Because the dominant noise components are generally the source resistance and the internal amplifier noise voltage, we can approximate the noise figure as:

$$NF = 10\log \left[1 + \frac{\left(e_n^2 + (I_N + \times R_S)^2 \right)}{4 kTR_S} \right] \quad (4)$$

Figure 42 shows the noise figure graph for the THS6062.

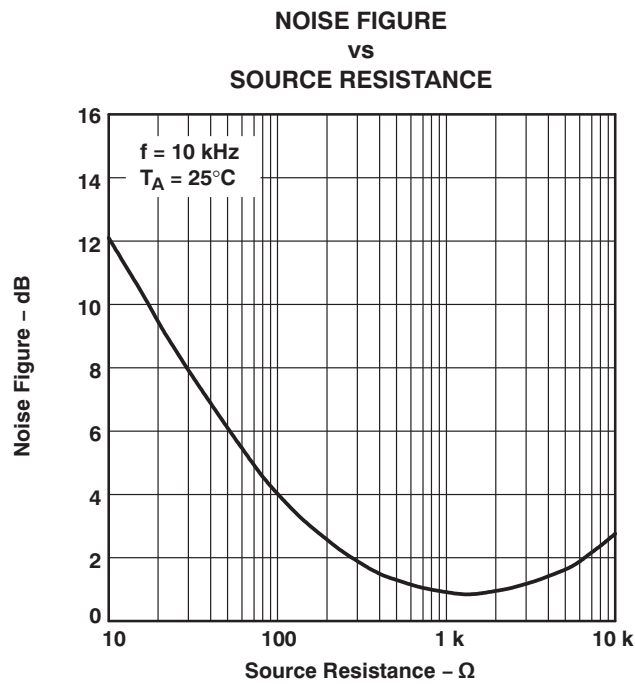


Figure 42. Noise Figure vs Source Resistance

OPTIMIZING FREQUENCY RESPONSE

Internal frequency compensation of the THS6062 was selected to provide very wide bandwidth performance and still maintain a very low noise floor. In order to meet these performance requirements, the THS6062 must have a minimum gain of 2 (–1). Because everything is referred to the noninverting terminal of an operational amplifier, the noise gain in a $G = -1$ configuration is the same as in a $G = 2$ configuration.

One of the keys to maintaining a smooth frequency response, and hence, a stable pulse response, is to pay particular attention to the inverting terminal. Any stray capacitance at this node causes peaking in the frequency response (see Figure 43 and Figure 44). There are two things that can be done to help minimize this effect. The first is to simply remove any ground planes under the inverting terminal of the amplifier. This also includes the trace that connects to this terminal. Additionally, the length of this trace should be minimized. The capacitance at this node causes a lag in the voltage being fed back due to the charging and discharging of the stray capacitance. If this lag becomes too long, the amplifier will not be able to correctly keep the noninverting terminal voltage at the same potential as the inverting terminal's voltage. Peaking and possibly oscillations will then occur.

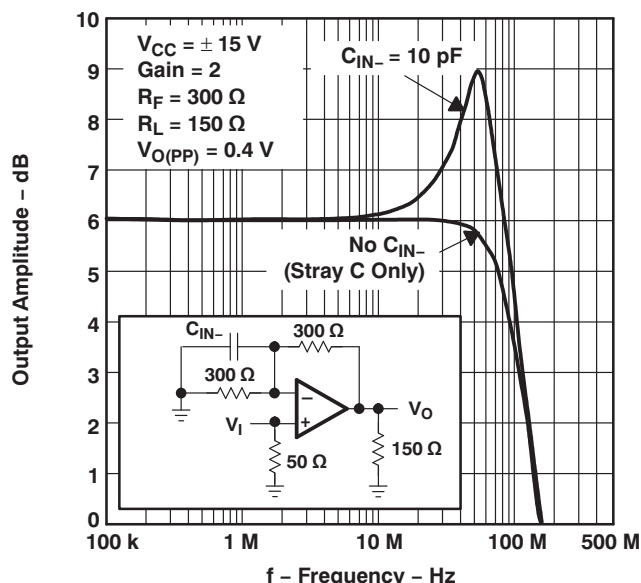


Figure 43.

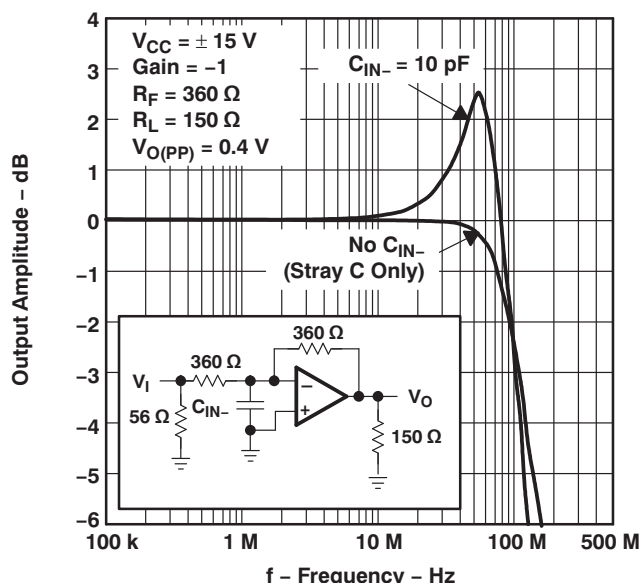


Figure 44.

The next thing that helps to maintain a smooth frequency response is to keep the feedback resistor (r_f) and the gain resistor (r_g) values fairly low. These two resistors are effectively in parallel when looking at the ac small-signal response. This is why in Figure 30, a feedback resistor of 3.9 k Ω with a gain resistor of 1 k Ω only shows a small peaking in the frequency response. The parallel resistance is only 800 Ω . This value, in conjunction with a very small stray capacitance test PCB, forms a zero on the edge of the amplifier's natural frequency response. To eliminate this peaking, all that needs to be done is to reduce the feedback and gain resistances. One other way to compensate for this stray capacitance is to add a small capacitor in parallel with the feedback resistor. This helps to neutralize the effects of the stray capacitance. To keep this zero out of the operating range, the stray capacitance and resistor value's time constant must be kept low. But, as can be seen in Figure 23 to Figure 28, a value too low starts to reduce the bandwidth of the amplifier. Table 1 shows some recommended feedback resistors to be used with the THS6062.

Table 1. Recommended Feedback Resistors

GAIN	R_f for $V_{CC} = \pm 15\text{ V}, \pm 5\text{ V}, 5\text{ V}$
2	300 Ω
–1	360 Ω
5	3.3 k Ω (low stray-c PCB only)

DRIVING A CAPACITIVE LOAD

Driving capacitive loads with high performance amplifiers is not a problem as long as certain precautions are taken. The first is to realize that the THS6062 has been internally compensated to maximize its bandwidth and slew rate performance. When the amplifier is compensated in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series with the output of the amplifier, as shown in [Figure 45](#). A minimum value of 20 Ω should work well for most applications. For example, in 75- Ω transmission systems, setting the series resistor value to 75 Ω both isolates any capacitance loading and provides the proper line impedance matching at the source end.

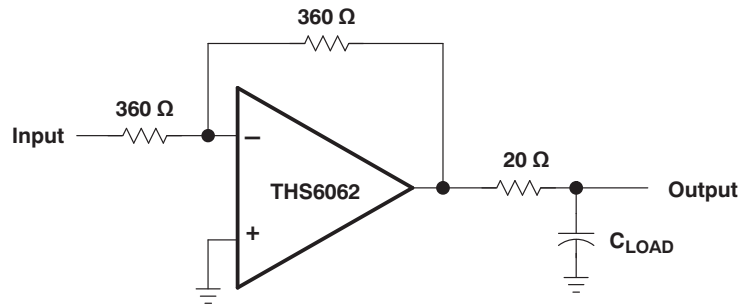


Figure 45. Driving a Capacitive Load

OFFSET VOLTAGE

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula are used to calculate the output offset voltage:

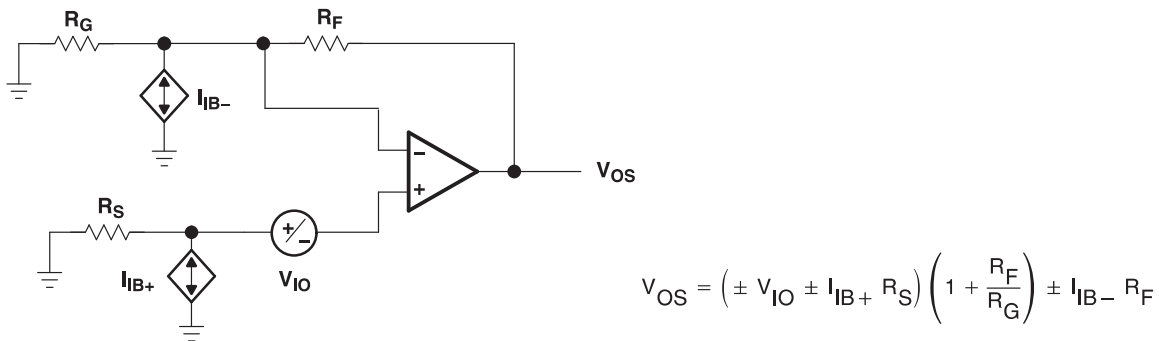


Figure 46. Output Offset Voltage Model

CIRCUIT LAYOUT CONSIDERATIONS

In order to achieve the high-frequency performance of the THS6062, it is essential that proper printed-circuit board high frequency design techniques be followed. A general set of guidelines is given below. In addition, a THS6062 evaluation board is available to use as a guide for layout or for evaluating the device performance.

- **Ground planes**—It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- **Proper power supply decoupling**—Use a 6.8- μ F tantalum capacitor in parallel with a 0.1- μ F ceramic capacitor on each supply terminal. It may be possible to share the tantalum capacitor among several amplifiers depending on the application, but a 0.1- μ F ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μ F capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- **Sockets**—Sockets are not recommended for high-speed operational amplifiers. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- **Short trace runs/compact part placements**—Optimum high frequency performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- **Surface-mount passive components**—Using surface-mount passive components is recommended for high frequency amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout, thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

GENERAL PowerPAD DESIGN CONSIDERATIONS

The THS6062 is available packaged in a thermally-enhanced DGN package, which is a member of the PowerPAD family of packages. This package is constructed using a downset leadframe upon which the die is mounted [see [Figure 47\(a\)](#) and [Figure 47\(b\)](#)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see [Figure 47](#)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the, heretofore, awkward mechanical methods of heat sinking.

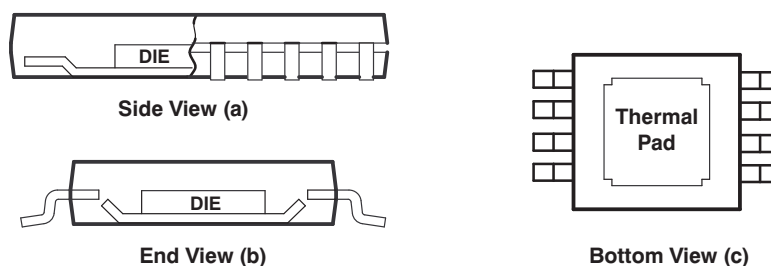


Figure 47. Views of Thermally Enhanced DGN Package

Although there are many ways to properly heat sink this device, the following steps illustrate the recommended approach.

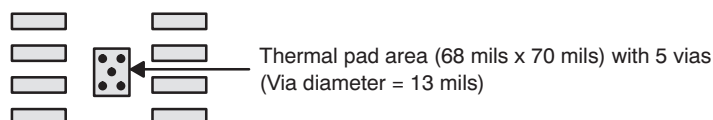


Figure 48. PowerPAD PCB Etch and Via Pattern

1. Prepare the PCB with a top side etch pattern as shown in [Figure 48](#). There should be etch for the leads as well as etch for the thermal pad.
2. Place five holes in the area of the thermal pad. These holes should be 13 mils in diameter. They are kept small so that solder wicking through the holes is not a problem during reflow.
3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the THS6062DGN IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
4. Connect all holes to the internal ground plane.
5. When connecting these holes to the ground plane, do not use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS6062DGN package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes exposed. The bottom-side solder mask should cover the five holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
8. With these preparatory steps in place, the THS6062DGN IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly

installed.

The actual thermal performance achieved with the THS6062DGN in its PowerPAD package depends on the application. In the example above, if the size of the internal ground plane is approximately 3 inches × 3 inches, then the expected thermal coefficient, θ_{JA} , is about 58.4°C/W. For comparison, the non-PowerPAD version of the THS6062 IC (SOIC) is shown. For a given θ_{JA} , the maximum power dissipation is shown in Figure 49 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right) \quad (5)$$

Where:

P_D = Maximum power dissipation of THS6062 IC (watts)

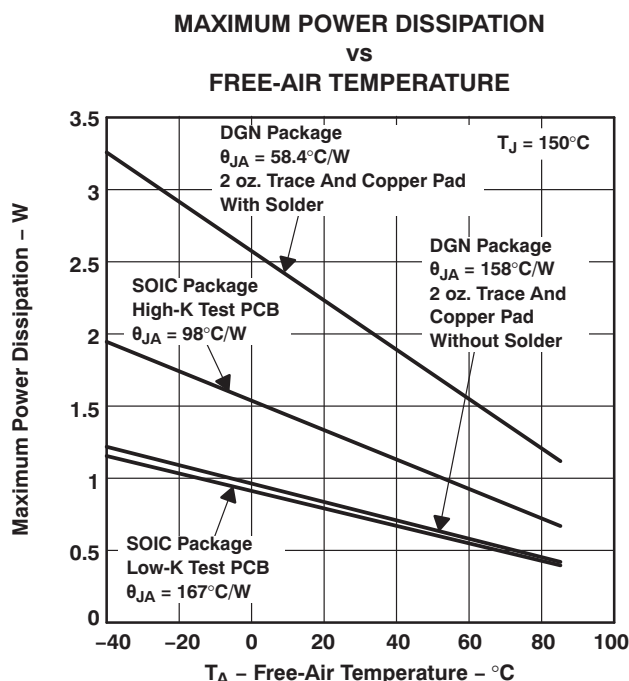
T_{MAX} = Absolute maximum junction temperature (150°C)

T_A = Free-ambient air temperature (°C)

$\theta_{JA} = \theta_{JC} + \theta_{CA}$

θ_{JC} = Thermal coefficient from junction to case

θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



NOTE: Results are with no air flow and PCB size = 3" × 3"

Figure 49. Maximum Power Dissipation vs Free-Air Temperature

More complete details of the PowerPAD installation process and thermal management techniques can be found in the Texas Instruments Technical Brief, PowerPAD Thermally Enhanced Package. This document can be found at the TI web site (www.ti.com) by searching on the key word PowerPAD. The document can also be ordered through your local TI sales office. Refer to literature number [SLMA002](#) when ordering.

The next thing that should be considered is the package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially a multi-amplifier device. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents. Figure 50 and Figure 51 show this effect, along with the quiescent heat, with an ambient air temperature of 50°C. When using $V_{CC} = 5\text{ V}$ or $\pm 5\text{ V}$, there is generally not a heat problem, even with SOIC packages. But, when using $V_{CC} = \pm 15\text{ V}$, the SOIC package is severely limited in the amount of heat it can dissipate. The other key factor when looking at these graphs is how the devices are mounted on the PCB. The PowerPAD devices are extremely useful for heat

dissipation. But the device should always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. Because the THS6062 is a dual amplifier, the sum of the RMS output currents and voltages should be used to choose the proper package.

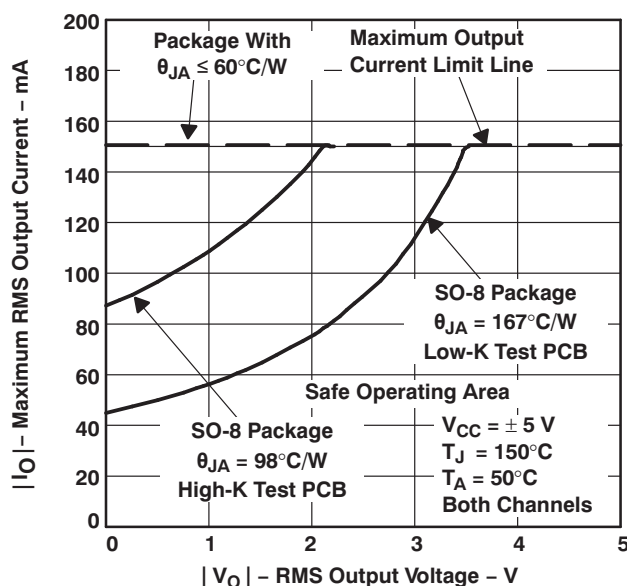


Figure 50.

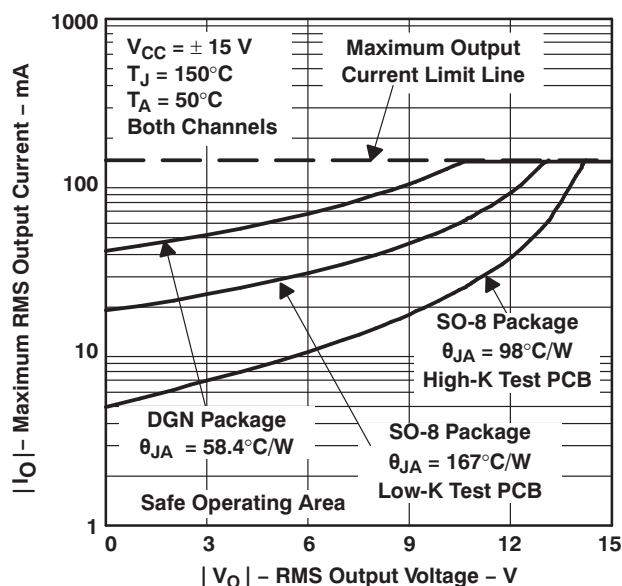


Figure 51.

EVALUATION BOARD

An evaluation board is available for the THS6062 ([SLOP221](#)). This board has been configured for very low parasitic capacitance in order to realize the full performance of the amplifier. For more information, refer to the *THS6062 EVM User's Guide* ([SLOU036](#)). To order the evaluation board contact your local TI sales office or distributor.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
THS6062CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	6062C	Samples
THS6062CDGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ABE	Samples
THS6062CDGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ABE	Samples
THS6062ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	6062I	Samples
THS6062IDGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		ABH	Samples
THS6062IDGNRG4	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABH	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS6062CDGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS6062IDGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS6062CDGNR	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0
THS6062IDGNR	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

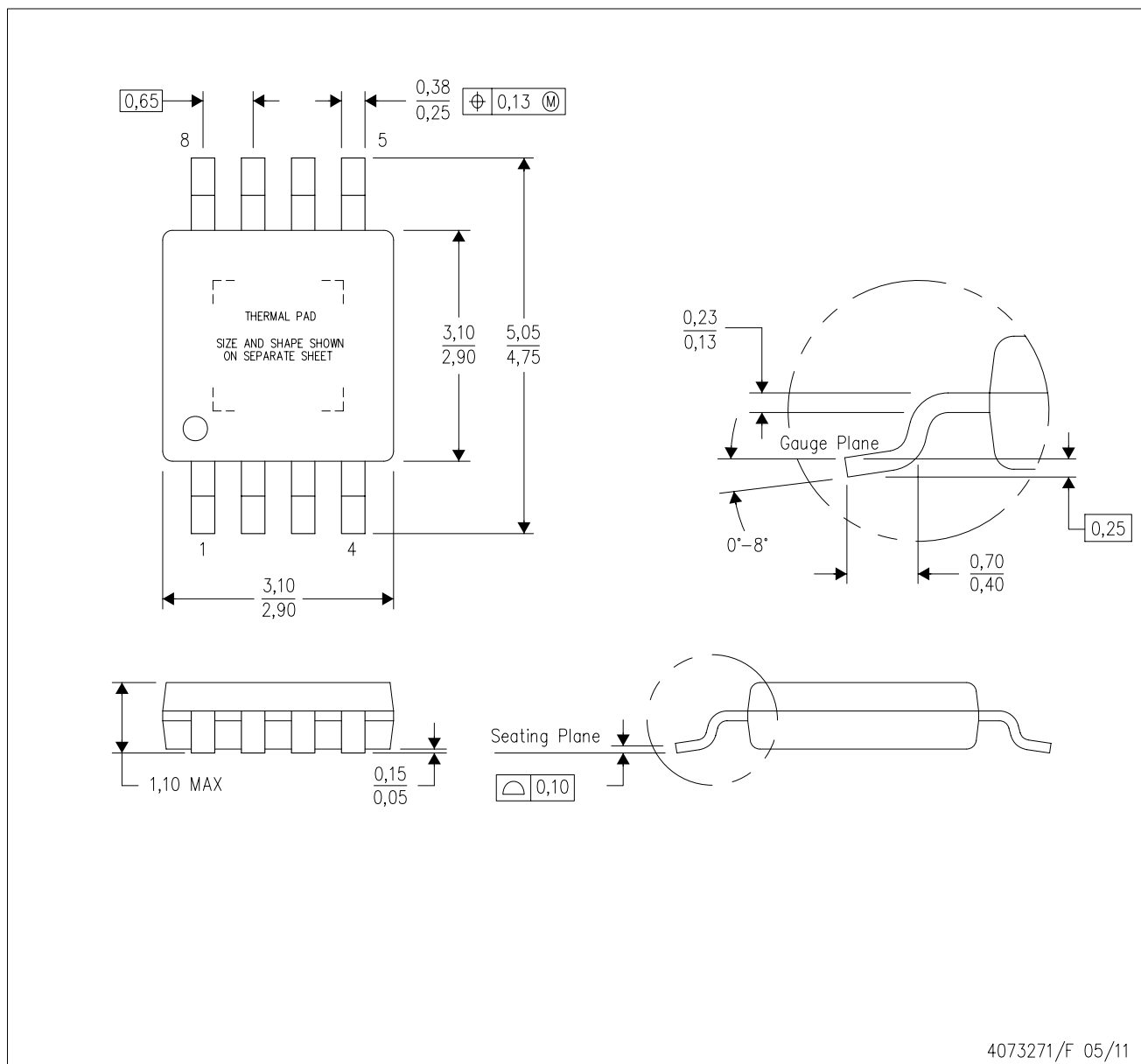
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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DGN (S-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Falls within JEDEC MO-187 variation AA-T

PowerPAD is a trademark of Texas Instruments.

DGN (S-PDSO-G8)

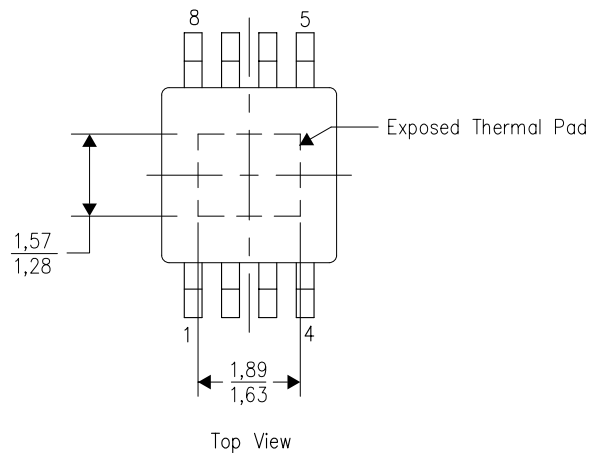
PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

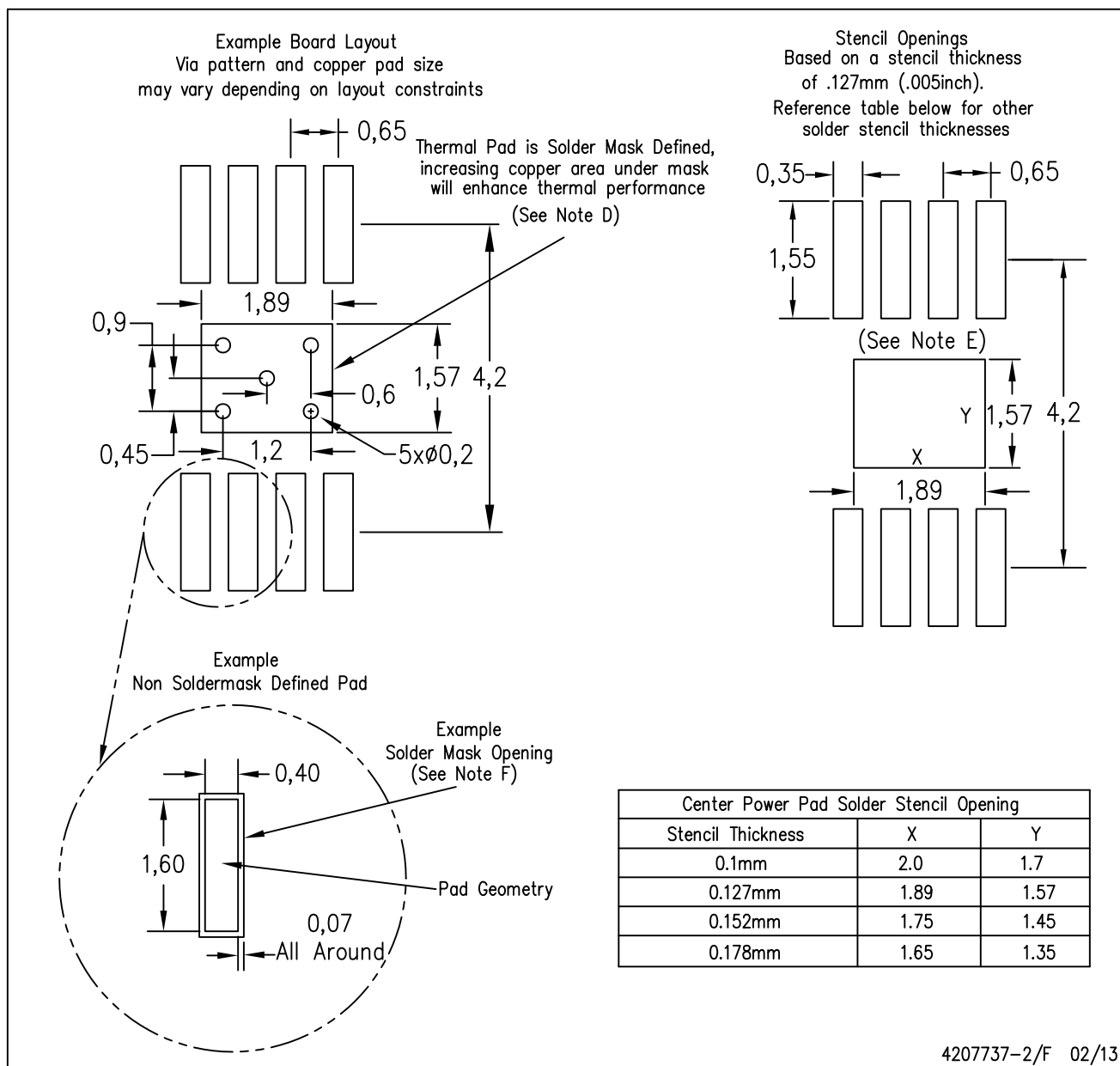
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NOTE: All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments

DGN (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



4207737-2/F 02/13

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PowerPAD is a trademark of Texas Instruments

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